

PLL Frequency Synthesizer ADF4106-EP

FEATURES

6.0 GHz bandwidth 2.7 V to 3.3 V power supply Separate charge pump supply (V_P) allows extended tuning voltage in 3 V systems Programmable dual-modulus prescaler 8/9, 16/17, 32/33, 64/65 Programmable charge pump currents Programmable antibacklash pulse width 3-wire serial interface Analog and digital lock detect Hardware and software power-down mode Support defense and aerospace applications (AQEC) Military temperature range (-55°C to +125°C) **Controlled manufacturing baseline** One assembly/test site **One fabrication site Enhanced product change notification Qualification data available upon request**

APPLICATIONS

Broadband wireless access Satellite systems Instrumentation Wireless LANS Base stations for wireless radios

GENERAL DESCRIPTION

The ADF4106-EP frequency synthesizer can be used to implement local oscillators in the up-conversion and downconversion sections of wireless receivers and transmitters. It consists of a low noise, digital phase frequency detector (PFD), a precision charge pump, a programmable reference divider, programmable A counter and B counter, and a dual-modulus prescaler (P/P + 1). The A (6-bit) counter and B (13-bit) counter, in conjunction with the dual-modulus prescaler (P/P + 1), implement an N divider (N = BP + A). In addition, the 14-bit reference counter (R counter) allows selectable REF_{IN} frequencies at the PFD input. A complete phase-locked loop (PLL) can be implemented if the synthesizer is used with an external loop filter and voltage controlled oscillator (VCO). Its very high bandwidth means that frequency doublers can be eliminated in many high frequency systems, simplifying system architecture and reducing cost.

Additional application and technical information can be found in the ADF4106 data sheet.





Rev. 0

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REVISION HISTORY

8/10—Revision 0: Initial Version

SPECIFICATIONS

 $AV_{DD} = DV_{DD} = 3 V \pm 10\%$, $AV_{DD} \le V_P \le 5.5 V$, AGND = DGND = CPGND = 0 V, $R_{SET} = 5.1 k\Omega$, dBm referred to 50 Ω , $T_A = T_{MAX}$ to T_{MIN} , unless otherwise noted.

Table 1.			
Parameter	B Version ¹	Unit	Test Conditions/Comments
RF CHARACTERISTICS			
RF Input Frequency (RF _{IN})	0.5/6.0	GHz min/max	For lower frequencies, ensure slew rate (SR) $>$ 320 V/µs
RF Input Sensitivity	-10/0	dBm min/max	
Maximum Allowable Prescaler Output Frequency ²	300	MHz max	P = 8
	325	MHz	P = 16
REF _{IN} CHARACTERISTICS			
REF _{IN} Input Frequency	20/300	MHz min/max	For f < 20 MHz, ensure SR > 50 V/μs
REF _{IN} Input Sensitivity ³	0.8/V _{DD}	V p-p min/max	Biased at AV _{DD} /2 ⁴
REF _{IN} Input Capacitance	10	pF max	
REF _{IN} Input Current	±100	μA max	
PHASE DETECTOR			
Phase Detector Frequency⁵	104	MHz max	ABP = 0, 0 (2.9 ns antibacklash pulse width)
CHARGE PUMP			
Ic Sink/Source			
High Value	5	mA typ	With $R_{SET} = 5.1 \text{ k}\Omega$
Low Value	625	μA typ	
Absolute Accuracy	2.5	% typ	With $R_{SET} = 5.1 \text{ k}\Omega$
R _{SET} Range	3.0/11	kΩ typ	
Icp Three-State Leakage	2	nA max	1 nA typical; T _A = 25°C
Sink and Source Current Matching	2	% typ	$0.5~V \leq V_{CP} \leq V_P - 0.5~V$
ICP VS. VCP	1.5	% typ	$0.5 \text{ V} \le \text{V}_{\text{CP}} \le \text{V}_{\text{P}} - 0.5 \text{ V}$
Ic₂ vs. Temperature	2	% typ	$V_{CP} = V_P/2$
LOGIC INPUTS			
V _⊮ , Input High Voltage	1.4	V min	
V _{IL} , Input Low Voltage	0.6	V max	
I _{INH} , I _{INL} , Input Current	±1	μA max	
C _{IN} , Input Capacitance	10	pF max	
LOGIC OUTPUTS			
V _{он} , Output High Voltage	1.4	V min	Open-drain output chosen, 1 k Ω pull-up resistor to 1.8 V
	$V_{\text{DD}} - 0.4$	V min	CMOS output chosen
Іон	100	μA max	
V _{OL} , Output Low Voltage	0.4	V max	Ι _{ΟL} = 500 μΑ
POWER SUPPLIES			
AV _{DD}	2.7/3.3	V min/V max	
DV _{DD}	AV _{DD}		
VP	AV _{DD} /5.5	V min/V max	$AV_{DD} \le V_P \le 5.5 V$
I_{DD}^{6} (AI _{DD} + DI _{DD})	11	mA max	9.0 mA typical
I_{DD}^{7} (AI _{DD} + DI _{DD})	11.5	mA max	9.5 mA typical
I_{DD}^{8} (AI _{DD} + DI _{DD})	13	mA max	10.5 mA typical
IP	0.4	mA max	$T_A = 25^{\circ}C$
Power-Down Mode ⁹ (Al _{DD} + DI _{DD})	10	μA typ	

Parameter	B Version ¹	Unit	Test Conditions/Comments
NOISE CHARACTERISTICS			
Normalized Phase Noise Floor (PN _{SYNTH}) ¹⁰	-223	dBc/Hz typ	PLL loop BW = 500 kHz
Normalized 1/f Noise (PN _{1_f}) ¹¹	-122	dBc/Hz typ	Measured at 10 kHz offset; normalized to 1 GHz
Phase Noise Performance ¹²			VCO output
900 MHz ¹³	-92.5	dBc/Hz typ	1 kHz offset and 200 kHz PFD frequency
5800 MHz ¹⁴	-76.5	dBc/Hz typ	1 kHz offset and 200 kHz PFD frequency
5800 MHz ¹⁵	-83.5	dBc/Hz typ	1 kHz offset and 1 MHz PFD frequency
Spurious Signals			
900 MHz ¹³	-90/-92	dBc typ	200 kHz/400 kHz and 200 kHz PFD frequency
5800 MHz ¹⁴	-65/-70	dBc typ	200 kHz/400 kHz and 200 kHz PFD frequency
5800 MHz ¹⁵	-70/-75	dBc typ	1 MHz/2 MHz and 1 MHz PFD frequency

¹ Operating temperature range is –55°C to +125°C.

² This is the maximum operating frequency of the CMOS counters. The prescaler value should be chosen to ensure that the RF input is divided down to a frequency that is less than this value.

 3 AV_{DD} = DV_{DD} = 3 V.

⁴ AC coupling ensures AV_{DD}/2 bias.

⁵ Guaranteed by design. Sample tested to ensure compliance.

 6 T_A = 25°C; AV_{DD} = DV_{DD} = 3 V; P = 16; RF_{IN} = 900 MHz.

 7 T_A = 25°C; AV_{DD} = DV_{DD} = 3 V; P = 16; RF_{IN} = 2.0 GHz.

 8 T_A = 25°C; AV_{DD} = DV_{DD} = 3 V; P = 32; RF_{IN} = 6.0 GHz.

 9 T_A = 25°C; AV_{DD} = DV_{DD} = 3.3 V; R = 16383; A = 63; B = 891; P = 32; RF_{IN} = 6.0 GHz.

¹⁰ The synthesizer phase noise floor is estimated by measuring the in-band phase noise at the output of the VCO and subtracting 20 log N (where N is the N divider value) and 10 log F_{PFD}. PN_{SYNTH} = PN_{TOT} - 10 log F_{PFD} - 20 log N.

¹¹ The PLL phase noise is composed of 1/f (flicker) noise plus the normalized PLL noise floor. The formula for calculating the 1/f noise contribution at an RF frequency, f_{RF} , and at a frequency offset, f, is given by $PN = P_{1,f} + 10\log(10 \text{ kHz/f}) + 20\log(f_{RF}/1 \text{ GHz})$. Both the normalized phase noise floor and flicker noise are modeled in ADIsimPLL.

¹² The phase noise is measured with the EVAL-ADF4106-EB1 evaluation board and the Agilent E4440A spectrum analyzer. The spectrum analyzer provides the REF_{IN} for the synthesizer (f_{REFOUT} = 10 MHz @ 0 dBm).

 13 f_{REFIN} = 10 MHz; f_{PFD} = 200 kHz; offset frequency = 1 kHz; f_{RF} = 900 MHz; N = 4500; loop B/W = 20 kHz.

 14 f_{REFIN} = 10 MHz; f_{PFD} = 200 kHz; offset frequency = 1 kHz; f_{RF} = 5800 MHz; N = 29,000; loop B/W = 20 kHz.

 15 f_{REFIN} = 10 MHz; f_{PFD} = 1 MHz; offset frequency = 1 kHz; f_{RF} = 5800 MHz; N = 5800; loop B/W = 100 kHz.

TIMING CHARACTERISITICS

 $AV_{DD} = DV_{DD} = 3 V \pm 10\%$, $AV_{DD} \le V_P \le 5.5 V$, AGND = DGND = CPGND = 0 V, $R_{SET} = 5.1 k\Omega$, dBm referred to 50 Ω , $T_A = T_{MAX}$ to T_{MIN} , unless otherwise noted.

1 4010 2.			
Parameter	Limit ¹ (B Version)	Unit	Test Conditions/Comments
t ₁	10	ns min	DATA to CLOCK Setup Time
t ₂	10	ns min	DATA to CLOCK Hold Time
t ₃	25	ns min	CLOCK High Duration
t4	25	ns min	CLOCK Low Duration
t5	10	ns min	CLOCK to LE Setup Time
t ₆	20	ns min	LE Pulse Width

¹ Operating temperature range (B Version) is -40°C to +85°C.

Timing Diagram

Table 2



Figure 2. Timing Diagram

ABSOLUTE MAXIMUM RATINGS

 $T_A = 25^{\circ}C$, unless otherwise noted.

Table 3.

Parameter	Rating
AV _{DD} to GND ¹	–0.3 V to + 3.6 V
AV _{DD} to DV _{DD}	–0.3 V to + 0.3 V
V _P to GND	–0.3 V to + 5.8 V
V _P to AV _{DD}	–0.3 V to + 5.8 V
Digital I/O Voltage to GND	-0.3 V to V _{DD} + 0.3 V
Analog I/O Voltage to GND	-0.3 V to V _P + 0.3 V
REFIN, RFINA, RFINB to GND	-0.3 V to V _{DD} + 0.3 V
Operating Temperature Range	
Industrial (B Version)	-40°C to +85°C
Storage Temperature Range	–65°C to +125°C
Maximum Junction Temperature	150°C
θ_{JA} Thermal Impedance	
16-Lead TSSOP	112°C/W
20-Lead LFCSP (Paddle Soldered)	30.4°C/W
Reflow Soldering	
Peak Temperature	260°C
Time at Peak Temperature	40 sec
Transistor Count	
CMOS	6425
Bipolar	303

 1 GND = AGND = DGND = 0 V.

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

This device is a high performance RF integrated circuit with an ESD rating of <2 kV, and it is ESD sensitive. Proper precautions should be taken for handling and assembly.

ESD CAUTION



ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

PIN CONFIGURATIONS AND FUNCTION DESCRIPTIONS



Table 4. Pin Function Descriptions

Pin No. TSSOP	Pin No. LFCSP	Mnemonic	Description
1	19	Rset	Connecting a resistor between this pin and CPGND sets the maximum charge pump output current. The nominal voltage potential at the R _{SET} pin is 0.66 V. The relationship between I _{CP} and R _{SET} is $I_{CPMAX} = \frac{25.5}{R_{SET}}$
			So, with $R_{SET} = 5.1 \text{ k}\Omega$, $I_{CP \text{ MAX}} = 5 \text{ mA}$.
2	20	СР	Charge Pump Output. When enabled, this provides $\pm I_{CP}$ to the external loop filter, which in turn drives the external VCO.
3	1	CPGND	Charge Pump Ground. This is the ground return path for the charge pump.
4	2, 3	AGND	Analog Ground. This is the ground return path of the prescaler.
5	4	RFıℕB	Complementary Input to the RF Prescaler. This point must be decoupled to the ground plane with a small bypass capacitor, typically 100 pF.
6	5	RFINA	Input to the RF Prescaler. This small signal input is ac-coupled to the external VCO.
7	6, 7	AV _{DD}	Analog Power Supply. This can range from 2.7 V to 3.3 V. Decoupling capacitors to the analog ground plane should be placed as close as possible to this pin. AV_{DD} must be the same value as DV_{DD} .
8	8	REFIN	Reference Input. This is a CMOS input with a nominal threshold of $V_{DD}/2$ and a dc equivalent input resistance of 100 k Ω . This input can be driven from a TTL or CMOS crystal oscillator or it can be ac-coupled.
9	9, 10	DGND	Digital Ground.
10	11	CE	Chip Enable. A logic low on this pin powers down the device and puts the charge pump output into three-state mode. Taking the pin high powers up the device, depending on the status of the power-down bit, F2.
11	12	CLK	Serial Clock Input. This serial clock is used to clock in the serial data to the registers. The data is latched into the 24-bit shift register on the CLK rising edge. This input is a high impedance CMOS input.
12	13	DATA	Serial Data Input. The serial data is loaded MSB first with the two LSBs being the control bits. This input is a high impedance CMOS input.
13	14	LE	Load Enable, CMOS Input. When LE goes high, the data stored in the shift registers is loaded into one of the four latches with the latch being selected using the control bits.
14	15	MUXOUT	This multiplexer output allows either the lock detect, the scaled RF, or the scaled reference frequency to be accessed externally.
15	16, 17		Digital Power Supply. This can range from 2.7 V to 3.3 V. Decoupling capacitors to the digital ground plane should be placed as close as possible to this pin. DV_{DD} must be the same value as AV_{DD} .
16	18	VP	Charge Pump Power Supply. This should be greater than or equal to V_{DD} . In systems where V_{DD} is 3 V, it can be set to 5.5 V and used to drive a VCO with a tuning range of up to 5 V.
		EP	Exposed Pad. The exposed pad must be connected to AGND.

TYPICAL PERFORMANCE CHARACTERISTICS

FREQ UNIT GHZ KEYWORD R PARAM TYPE S IMPEDANCE 50Ω DATA FORMAT MA					
FREQ	MAGS11	ANGS11	FREQ	MAGS11 AN	GS11
0.500	0.89148	-17.2820	3.300	0.42777	-102.748
0.600	0.88133	- 20.6919	3.400	0.42859	-107.167
0.700	0.67152	- 24.0300	3.500	0.43305	-111.003
0.000	0.00000	-27.3220	3.000	0.43649	122 956
1 000	0.04911	-31,0050	3.700	0.44475	120.200
1 100	0.82374	-38 5574	3 900	0.45223	-136 744
1 200	0.80871	-41 9093	4 000	0.45555	-142 766
1.300	0 79176	- 45 6990	4 100	0.45313	-149 269
1.400	0.77205	-49.4185	4.200	0.45622	-154.884
1.500	0.75696	-52.8898	4.300	0.45555	-159.680
1.600	0.74234	-56.2923	4.400	0.46108	-164.916
1.700	0.72239	-60.2584	4.500	0.45325	-168.452
1.800	0.69419	-63.1446	4.600	0.45054	-173.462
1.900	0.67288	-65.6464	4.700	0.45200	-176.697
2.000	0.66227	-68.0742	4.800	0.45043	178.824
2.100	0.64758	-71.3530	4.900	0.45282	174.947
2.200	0.62454	-75.5658	5.000	0.44287	170.237
2.300	0.59466	-79.6404	5.100	0.44909	166.617
2.400	0.55932	-82.8246	5.200	0.44294	162.786
2.500	0.52256	-85.2795	5.300	0.44558	158.766
2.600	0.48754	-85.6298	5.400	0.45417	153.195
2.700	0.40411	-00.1854	5.500	0.40038	147.721
2.000	0.40770	-00.4997	5 700	0.47120	139.700
2.500	0.44039	-00.0000	5 800	0.47439	125 782
3 100	0.43810	-95 4087	5 900	0.50637	121 110
3.200	0.43269	-99.1282	6.000	0.52172	115.400

Figure 5. S-Parameter Data for the RF Input

09272-005



FREQUENCY Figure 7. Phase Noise (900 MHz, 200 kHz, and 20 kHz)

900MHz

1kHz

–1kHz

–2kHz



Figure 8. Integrated Phase Noise (900 MHz, 200 kHz, and 20 kHz)



Figure 9. Reference Spurs (900 MHz, 200 kHz, and 20 kHz)



Figure 10. Phase Noise (5.8 GHz, 1 MHz, and 100 kHz)

09272-007

2kHz





Figure 12. Reference Spurs (5.8 GHz,1 MHz, and 100 kHz)



Figure 13. Phase Noise (5.8 GHz, 1 MHz, and 100 kHz) vs. Temperature



Figure 14. Reference Spurs vs. V_{TUNE} (5.8 GHz, 1 MHz, and 100 kHz)







PCB DESIGN GUIDELINES FOR CHIP SCALE PACKAGE

The lands on the 20-lead LFCSP (CP-20) are rectangular. The printed circuit board (PCB) pad for these should be 0.1 mm longer than the package land length and 0.05 mm wider than the package land width. The land should be centered on the pad. This ensures that the solder joint size is maximized. The bottom of the LFCSP has a central thermal pad.

The thermal pad on the PCB should be at least as large as this exposed pad. On the PCB, there should be a clearance of at least 0.25 mm between the thermal pad and the inner edges of the pad pattern. This ensures that shorting is avoided.

Thermal vias may be used on the PCB thermal pad to improve thermal performance of the package. If vias are used, they should be incorporated in the thermal pad at 1.2 mm pitch grid. The via diameter should be between 0.3 mm and 0.33 mm, and the via barrel should be plated with 1 oz. copper to plug the via.

The user should connect the PCB thermal pad to AGND.

OUTLINE DIMENSIONS



ORDERING GUIDE

Model ¹	Temperature Range	Package Description	Package Option
ADF4106-SRU-EP	-40°C to + 125°C	16-Lead Thin Shrink Small Outline Package [TSSOP]	RU-16
ADF4106-SRU-EP-R7	-40°C to + 125°C	16-Lead Thin Shrink Small Outline Package [TSSOP]	RU-16
ADF4106-SCPZ-EP	-40°C to + 125°C	20-Lead Lead Frame Chip Scale Package [LFCSP_VQ]	CP-20-1
ADF4106-SCPZ-EP-R7	–40°C to + 125°C	20-Lead Lead Frame Chip Scale Package [LFCSP_VQ]	CP-20-1

 1 Z = RoHS Compliant Part.

NOTES

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